

Product Summary

- V_{DS} -30V
- I_D -40A
- $R_{DS(ON)}$ (at $V_{GS}=-20V$) < 13mohm
- $R_{DS(ON)}$ (at $V_{GS}=-10V$) < 15mohm
- $R_{DS(ON)}$ (at $V_{GS}=-4.5V$) < 25mohm

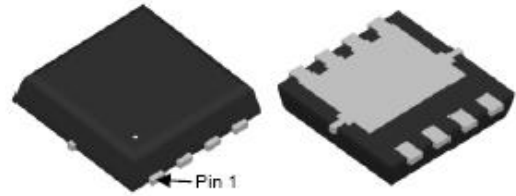
General Description

- Trench Power LV MOSFET technology
- High density cell design for Low $R_{DS(ON)}$
- High Speed switching

Applications

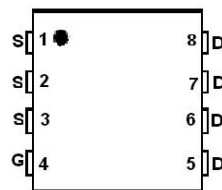
- Battery protection
- Power management
- Load switch

Package

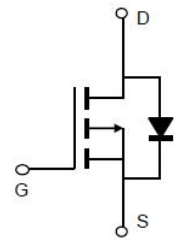


Top View

Bottom View



pin assignment



Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
LX33F40P30	F1	40P03	5000	10000	50000	13" reel

Absolute Maximum Ratings ($T_A=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Maximum	Unit
Drain-source Voltage	V_{DS}	-30	V
Gate-source Voltage	V_{GS}	± 25	V
Drain Current	$T_A=25^{\circ}C$ @ Steady State	-40	A
	$T_A=70^{\circ}C$ @ Steady State	-33	
Pulsed Drain Current ^A	I_{DM}	-160	A
Single Pulse Avalanche Energy @L=0.5mH ^B	E_{AS}	72	mJ
Total Power Dissipation @ $T_A=25^{\circ}C$ ^C	P_D	32	W
Thermal Resistance Junction-to-Ambient @ Steady State ^D	$R_{\theta JC}$	4.0	$^{\circ}C/W$
Junction and Storage Temperature Range	T_J, T_{STG}	-55~+150	$^{\circ}C$



Electrical Characteristics ($T_J=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=-250\mu A$	-30			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-30V, V_{GS}=0V, T_C=25^{\circ}\text{C}$			-1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS}= \pm 25V, V_{DS}=0V$			± 100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}= V_{GS}, I_D=-250\mu A$	-1.2	-1.8	-2.8	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}= -20V, I_D=-20A$		8.6	13	m Ω
		$V_{GS}= -10V, I_D=-15A$		9.8	15	
		$V_{GS}= -6.0V, I_D=-12A$		12.1	22	
		$V_{GS}= -4.5V, I_D=-10A$		15.5	25	
Diode Forward Voltage	V_{SD}	$I_S=-20A, V_{GS}=0V$			-1.2	V
Dynamic Parameters						
Input Capacitance	C_{iss}	$V_{DS}=-15V, V_{GS}=0V, f=1\text{MHz}$		2152		pF
Output Capacitance	C_{oss}			308		
Reverse Transfer Capacitance	C_{rss}			242		
Gate Resistance	R_g	$f= 1\text{MHz}$			20	Ω
Switching Parameters						
Total Gate Charge	Q_g	$V_{GS}=-10V, V_{DS}=-15V, I_D=-12A$		40.1		nC
Gate Source Charge	Q_{gs}			8.4		
Gate Drain Charge	Q_{gd}			8.6		
Reverse Recovery Charge	Q_{rr}	$I_F= -12A, di/dt=100A/\mu s$		7.8		ns
Reverse Recovery Time	t_{rr}			18		
Turn-on Delay Time	$t_{D(on)}$	$V_{GS}=-10V, V_{DD}=-15V, I_D=-1A, R_{GEN}=2.5\Omega$		8		ns
Turn-on Rise Time	t_r			19		
Turn-off Delay Time	$t_{D(off)}$			75		
Turn-off Fall Time	t_f			46		

A. Pulse Test: Pulse Width $\leq 300\mu s$, Duty cycle $\leq 2\%$.

B. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design, while $R_{\theta JA}$ is determined by the board design. The maximum rating presented here is based on mounting on a 1 in 2 pad of 2oz copper.

Typical Performance Characteristics

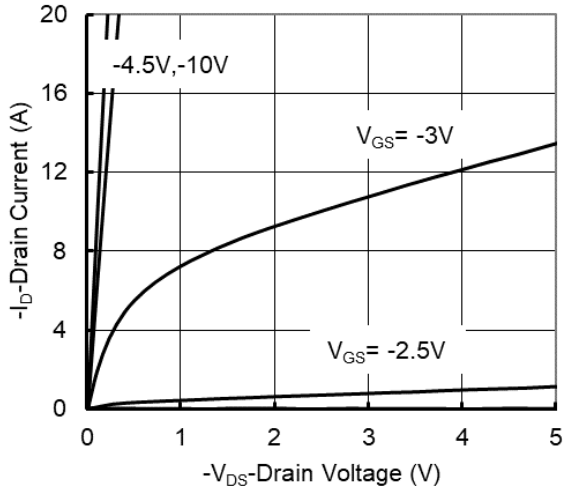


Figure 1. Output Characteristics

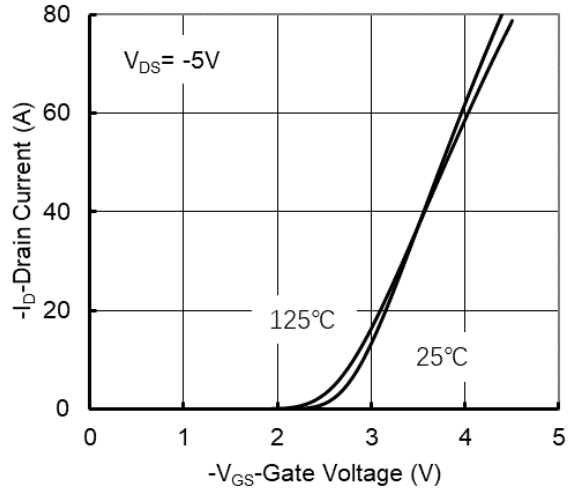


Figure 2. Transfer Characteristics

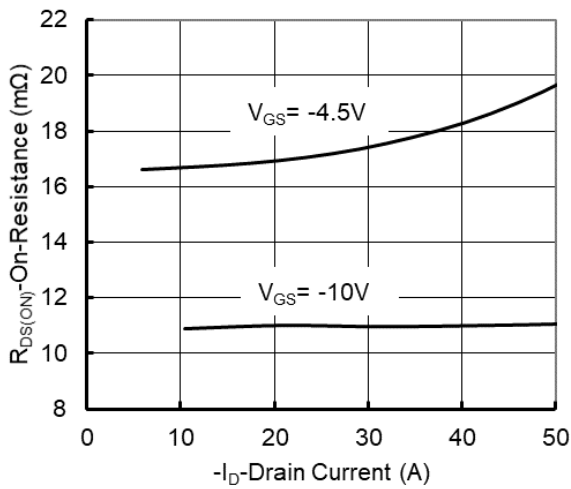


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

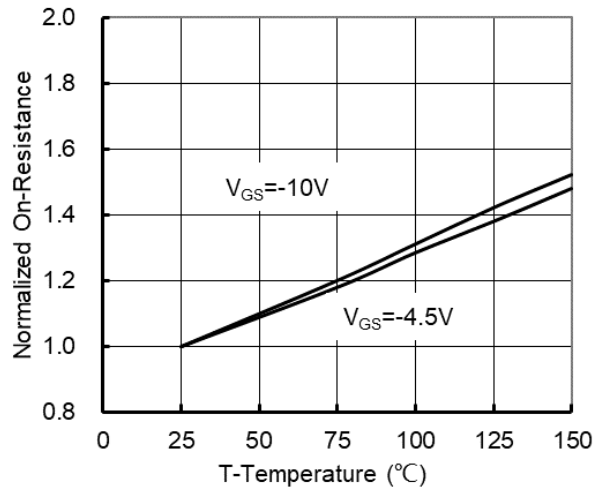


Figure 4. On-Resistance vs. Junction Temperature

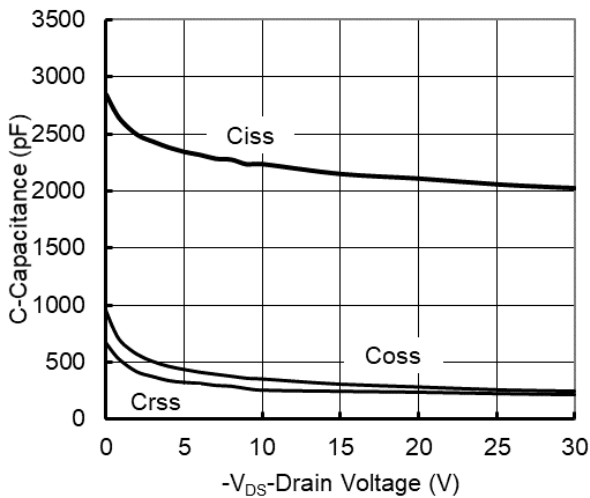


Figure 5. Capacitance Characteristics

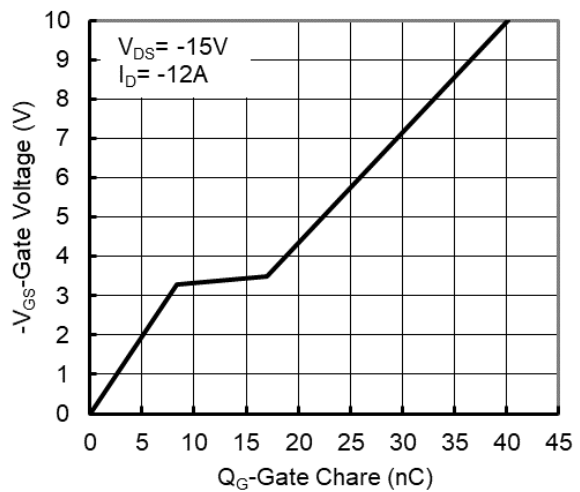


Figure 6. Gate Charge

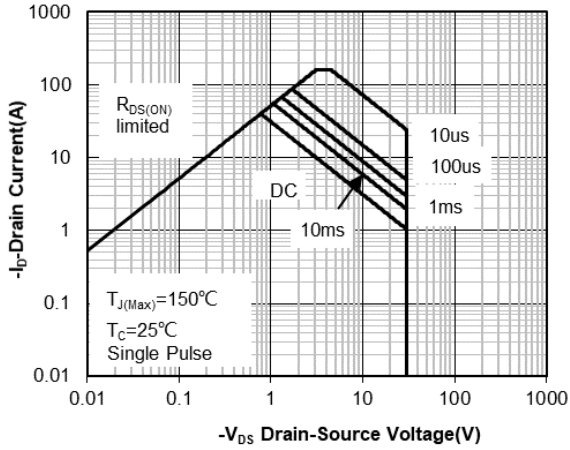


Figure 7. Safe Operation Area

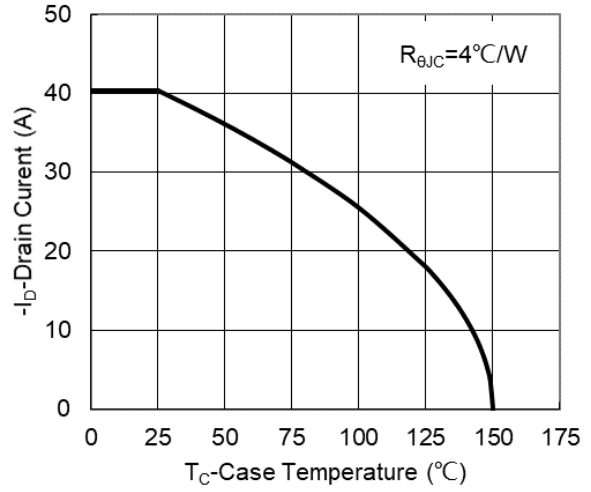


Figure 8. Maximum Continuous Drain Current vs Case Temperature

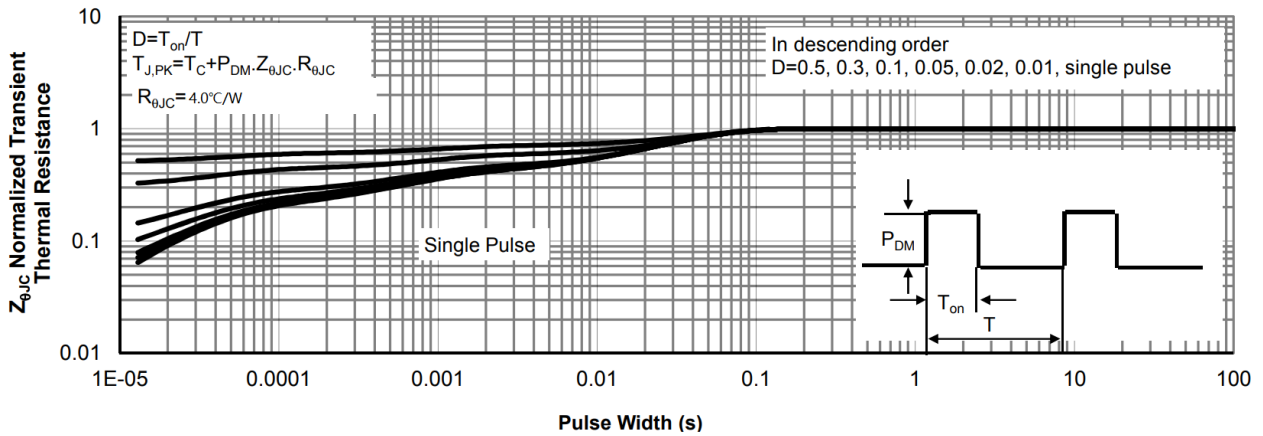
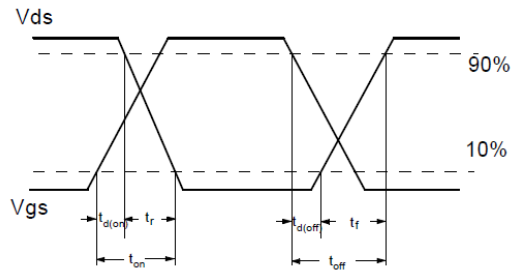
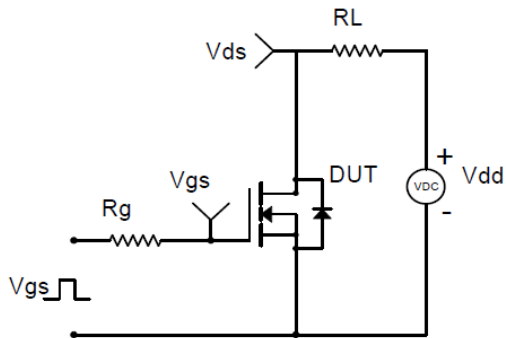
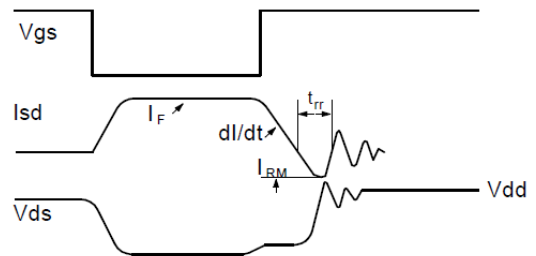
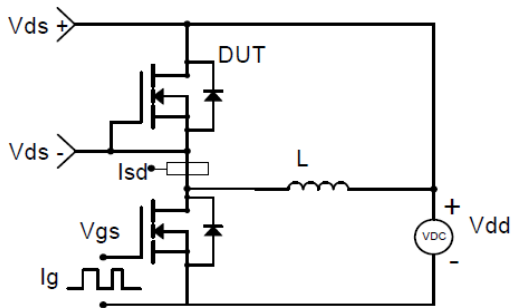


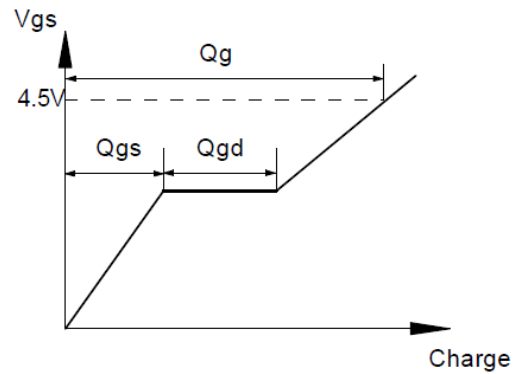
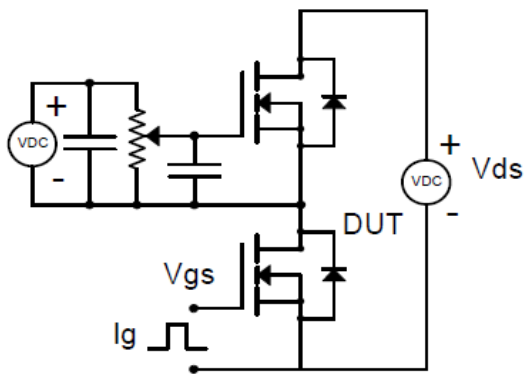
Figure 9. Normalized Maximum Transient Thermal Impedance



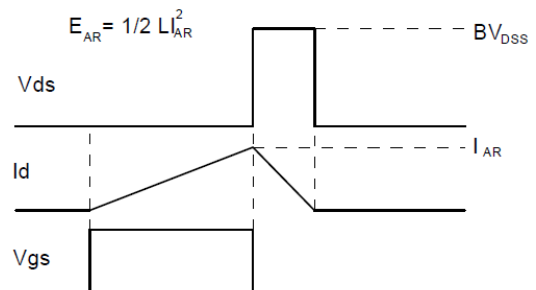
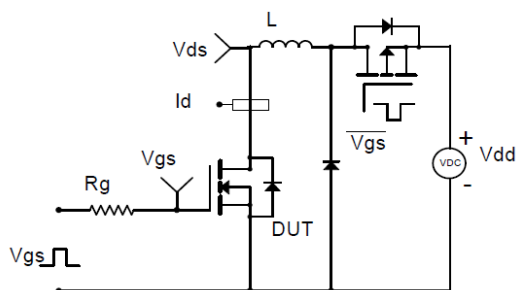
Resistive Switching Test Circuit & Waveforms



Diode Recovery Test Circuit & Waveforms

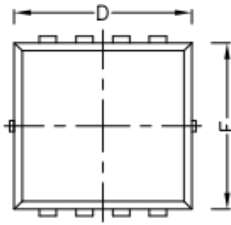


Gate Charge Test Circuit & Waveform

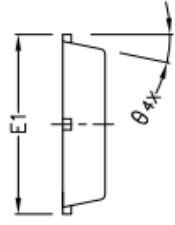


Unclamped Inductive Switching (UIS) Test Circuit & Waveforms

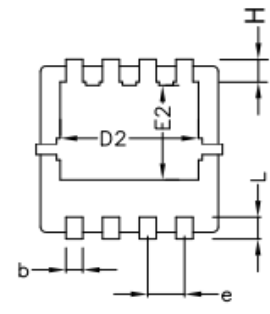
PDFN 3*3-8L Package Outline Dimensions



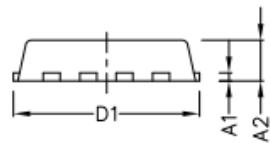
TOP VIEW



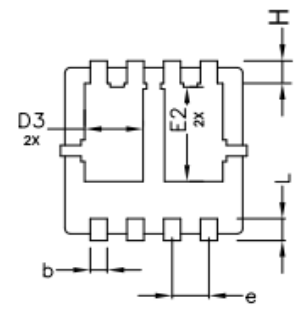
SIDE VIEW



BOTTOM VIEW
OPTION 1



SIDE VIEW



BOTTOM VIEW
OPTION 2

COMMON DIMENSIONS (UNITS OF MEASURE IS mm)			
	MIN	NORMAL	MAX
A1	0.152 BSC		
A2	0.700	0.800	0.900
b	0.250	-	0.400
D	3.050	3.150	3.250
D1	3.200	3.300	3.400
D2	2.350	2.450	2.550
D3	0.935	1.035	1.135
E1	3.200	3.300	3.400
E	2.900	3.000	3.100
E2	1.635	1.735	1.835
e	0.650 REF		
L	0.300	0.400	0.500
H	0.250	-	0.630
theta	12° TYPE		